ELECTRONIC INFORMATION DISCLOSURE STATEMENT

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Title of Invention

PROGRAMMABLE METAL TO METAL ANTIFUSE EMPLOYING

CARBON CONTAINING ANTIFUSE MATERIAL

Application Number:

10/784903

Confirmation Number:

6148

First Named Applicant:

A Issaq

Attorney Docket Number:

Search string:

(4442507 or 4543594 or 4823181 or 4881114 or 4899205 or 5070384 or 5171715 or 5181096 or 5196724 or 5272101 or 5308795 or 5365104 or 5411917 or 5576576 or 5592016 or 5763898 or 5780323 or 5789764 or 6114714 or 6437365 or

20020100907).pn.

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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Signature

Examiner Name	Date
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